NSN 5961-01-424-3174

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-424-3174

Inclosure Material:
Plastic
Internal Configuration:
Junction contact
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 breakdown voltage, collector-to-emitter, base open
Current Rating Per Characteristic:
6.00 amperes source cutoff current
Maximum Operating Tempurature Per Measurement Point:
165.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0